



ES2A thru ES2M

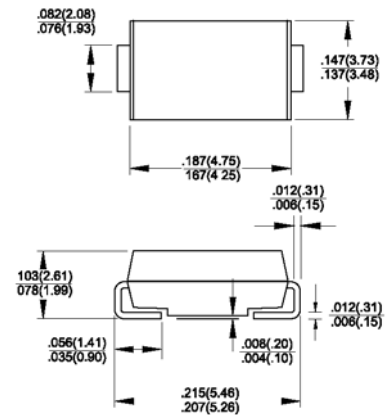
Super Fast Surface Mount Rectifiers
Reverse Voltage 50 to 1000 Volts Forward Current 2.0 Amperes

Features

- ◆ Glass passivated junction chip
- ◆ For surface mounted application
- ◆ Low profile package
- ◆ Built-in strain relief
- ◆ Ideal for automated placement
- ◆ Easy pick and place
- ◆ Superfast recovery time for high efficiency
- ◆ Glass passivated chip junction
- ◆ High temperature soldering:
250°C/10 seconds at terminals
- ◆ Plastic material used carries Underwriters Laboratory
Classification 94V-O



DO-214AA (SMB)



Mechanical Data

- ◆ Cases: Molded plastic
- ◆ Terminals: Solder plated
- ◆ Polarity: Indicated by cathode band
- ◆ Weight: 0.003 ounce, 0.093 gram

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Parameter	Symbols	ES 2A	ES 2B	ES 2C	ES 2D	ES 2F	ES 2G	ES 2J	ES 2K	ES 2M	Units	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	600	800	1000	Volts	
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	420	560	700	Volts	
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	600	800	1000	Volts	
Maximum average forward rectified current See Fig. 1	I_{AV}	2.0									Amps	
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50.0									Amps	
Maximum instantaneous forward voltage @ 2.0A	V_F	0.95			1.3			1.7			Volts	
Maximum DC reverse current @ $T_J=25^\circ\text{C}$ at rated DC blocking voltage @ $T_J=100^\circ\text{C}$	I_R					10.0			350			μA μA
Maximum reverse recovery time (Note 1)	t_{rr}					35						nS
Typical junction capacitance (Note 2)	C_J	25							20			pF
Typical thermal resistance (Note 3)	$R_{\theta JA}$ $R_{\theta JL}$					75			20			$^\circ\text{C/W}$
Operating junction temperature range	T_J	-55 to +150									$^\circ\text{C}$	
Storage temperature range	T_{STG}	-55 to +150									$^\circ\text{C}$	

- Notes:**
1. Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$
 2. Measured at 1 MHz and Applied $V_R=4.0$ Volts
 3. Units Mounted on P.C.B. 5.0 x 5.0mm (0.013mm thick) Pad Areas

RATINGS AND CHARACTERISTIC CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

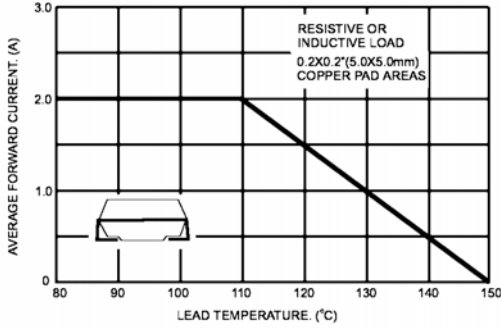


FIG.2- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

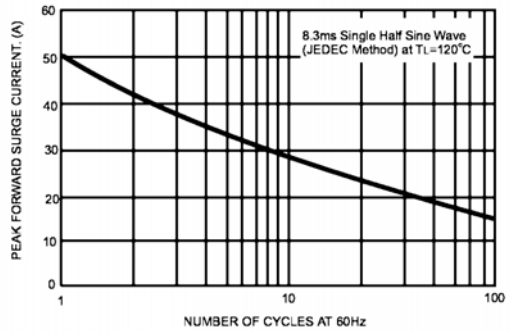


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

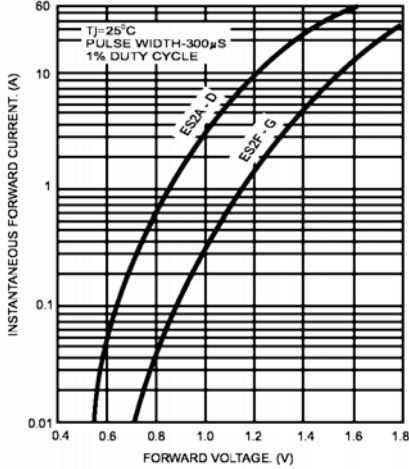


FIG.4- TYPICAL REVERSE CHARACTERISTICS

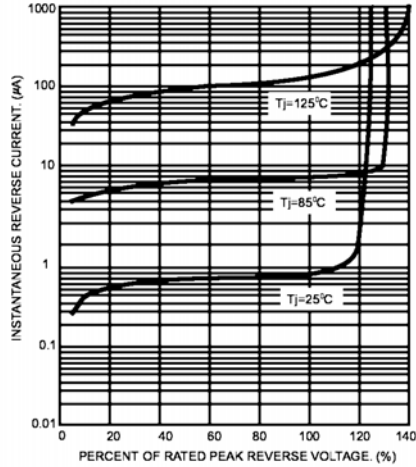


FIG.5- TYPICAL JUNCTION CAPACITANCE

